

### FEATURES

- Double Side Cooling
- High Surge Capability

### APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- DC Motor Control
- Welding
- Battery Chargers

### VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages $V_{DRM}$ and $V_{DRM}$ V	Conditions
DCR1594SW28	2800	$T_{vj} = 0^\circ$ to $125^\circ\text{C}$ , $I_{DRM} = I_{RRM} = 400\text{mA}$ , $V_{DRM}, V_{RRM} t_p = 10\text{ms}$ , $V_{DSM} \& V_{RSM} =$ $V_{DRM} \& V_{RRM} + 100\text{V}$ respectively
DCR1594SW27	2700	
DCR1594SW26	2600	
DCR1594SW25	2500	
DCR1594SW24	2400	
DCR1594SW23	2300	

Lower voltage grades available.

### KEY PARAMETERS

$V_{DRM}$		2800V
$I_{T(AV)}$	(max)	3875A
$I_{TSM}$	(max)	62500A
$dV/dt$ *		1000V/ $\mu\text{s}$
$dI/dt$		400A/ $\mu\text{s}$

\* Higher  $dV/dt$  selections available

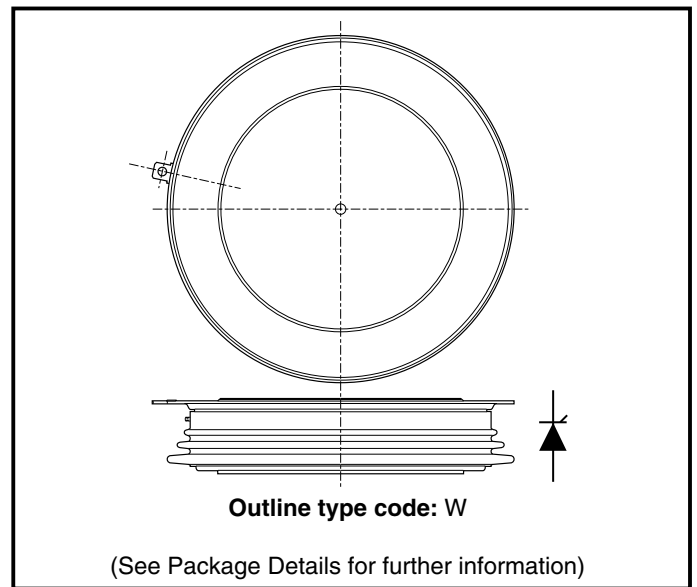


Fig. 1 Package outline

### ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

**DCR1594SW25**

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

## CURRENT RATINGS

$T_{case} = 60^{\circ}\text{C}$  unless stated otherwise.

Symbol	Parameter	Test Conditions	Max.	Units
<b>Double Side Cooled</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	3875	A
$I_{T(RMS)}$	RMS value	-	6087	A
$I_T$	Continuous (direct) on-state current	-	5439	A
<b>Single Side Cooled</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	2478	A
$I_{T(RMS)}$	RMS value	-	3892	A
$I_T$	Continuous (direct) on-state current	-	3199	A

$T_{case} = 80^{\circ}\text{C}$  unless stated otherwise.

Symbol	Parameter	Test Conditions	Max.	Units
<b>Double Side Cooled</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	3035	A
$I_{T(RMS)}$	RMS value	-	4765	A
$I_T$	Continuous (direct) on-state current	-	4125	A
<b>Single Side Cooled</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	1890	A
$I_{T(RMS)}$	RMS value	-	2970	A
$I_T$	Continuous (direct) on-state current	-	2405	A

**SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
$I_{TSM}$	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	50	kA
$I^2t$	$I^2t$ for fusing	$V_R = 50\% V_{RRM}$ - 1/4 sine	$12.5 \times 10^6$	A <sup>2</sup> s
$I_{TSM}$	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	62.5	kA
$I^2t$	$I^2t$ for fusing	$V_R = 0$	$19.5 \times 10^6$	A <sup>2</sup> s

**THERMAL AND MECHANICAL RATINGS**

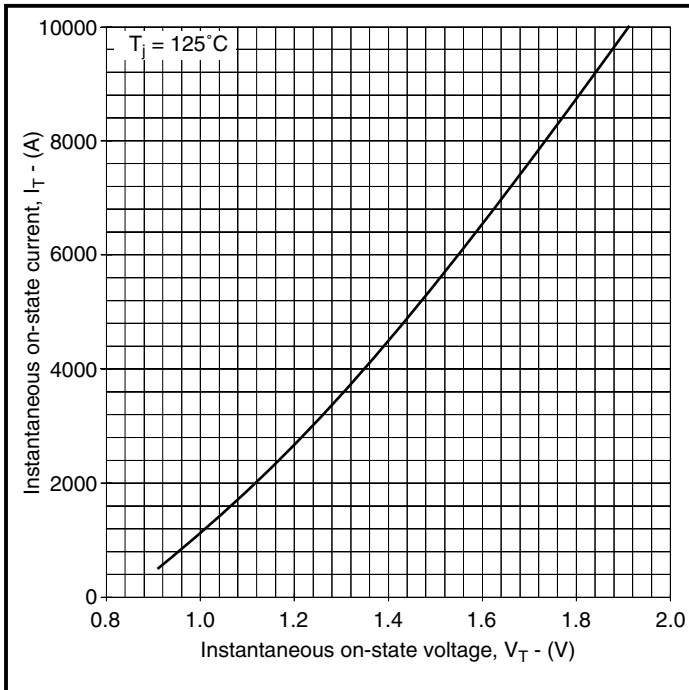
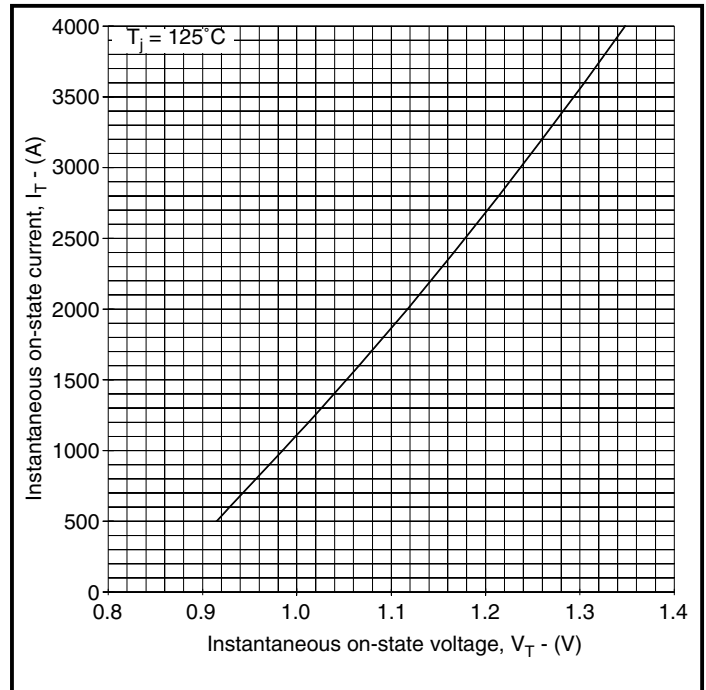
Symbol	Parameter	Test Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	DC	-	0.008	$^{\circ}CW$
		Single side cooled	Anode DC	-	0.016	$^{\circ}CW$
			Cathode DC	-	0.016	$^{\circ}CW$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 70.0kN	Double side	-	0.001	$^{\circ}CW$
		(with mounting compound)	Single side	-	0.002	$^{\circ}CW$
$T_{vj}$	Virtual junction temperature	On-state (conducting)		-	135	$^{\circ}C$
		Reverse (blocking)		-	125	$^{\circ}C$
$T_{stg}$	Storage temperature range			-55	125	$^{\circ}C$
$F_m$	Clamping force			63.0	77.0	kN

## SURGE RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
$I_{RRM}/I_{RRM}$	Peak reverse and off-state current	At $V_{RRM}/V_{DRM}$ , $T_{case} = 125^{\circ}C$	-	400	mA	
dV/dt	Max. linear rate of rise of off-state voltage	To 67% $V_{DRM}$ , $T_j = 125^{\circ}C$ , Gate open	-	1000	V/ $\mu$ s	
dl/dt	Rate of rise of on-state current	From 67% $V_{DRM}$ to $2 \times I_{T(AV)}$	Repetitive 50Hz	-	250	A/ $\mu$ s
		Gate source 30V, 10 $\Omega$ , $t_r \leq 0.5\mu$ s, $T_j = 125^{\circ}C$	Non-repetitive	-	400	A/ $\mu$ s
$V_{T(TO)}$	Threshold voltage	At $T_{vj} = 125^{\circ}C$	-	0.94	V	
$r_T$	On-state slope resistance	At $T_{vj} = 125^{\circ}C$	-	0.099	m $\Omega$	
$t_{gd}$	Delay time	$V_D = 67\% V_{DRM}$ , gate source 30V, 15 $\Omega$ $t_r = 0.5\mu$ s, $T_j = 25^{\circ}C$	0.5	2.0	$\mu$ s	
$t_q$	Turn-off time	$I_T = 5000A$ , $t_p = 3.5ms$ , $T_j = 125^{\circ}C$ , $V_R = 900V$ , $dI_{RR}/dt = 4A/\mu$ s, $V_{DR} = 67\% V_{DRM}$ , $dV_{DR}/dt = 20V/\mu$ s linear	450	900	$\mu$ s	
$I_L$	Latching current	$T_j = 25^{\circ}C$ , $V_D = 5V$	100	1000	mA	
$I_H$	Holding current	$T_j = 25^{\circ}C$ , $R_{G-K} = \infty$ , $I_{TM} = 500A$ , $I_T = 5A$	50	250	mA	

**GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
$V_{GT}$	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	4	V
$I_{GT}$	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	400	mA
$V_{GD}$	Gate non-trigger voltage	At $V_{DRM}, T_{case} = 125^{\circ}C$	0.25	V
$V_{FGM}$	Peak forward gate voltage	Anode positive with respect to cathode	30	V
$V_{FGN}$	Peak forward gate voltage	Anode negative with respect to cathode	0.25	V
$V_{RGM}$	Peak reverse gate voltage	-	5	V
$I_{FGM}$	Peak forward gate current	Anode positive with respect to cathode	30	A
$P_{GM}$	Peak gate power	See table fig. 8 and 9	150	W
$P_{G(AV)}$	Mean gate power	-	10	W

**CURVES**

**Fig.2 Maximum (limit) on-state characteristics**

**Fig.3 Maximum (limit) on-state characteristics**
 **$V_{TM}$  EQUATION**

$$V_{TM} = A + B \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

Where  $A = 1.152158$   
 $B = -0.08401428$   
 $C = 3.351054 \times 10^{-5}$   
 $D = 0.01199439$

these values are valid for  $T_j = 125^{\circ}C$  for  $I_T$  500A to 10000A

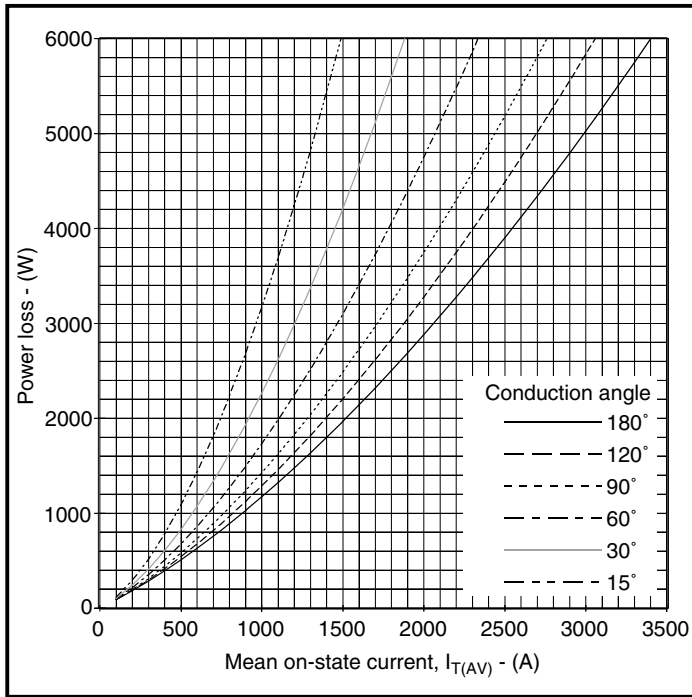


Fig.4 Sine wave power dissipation

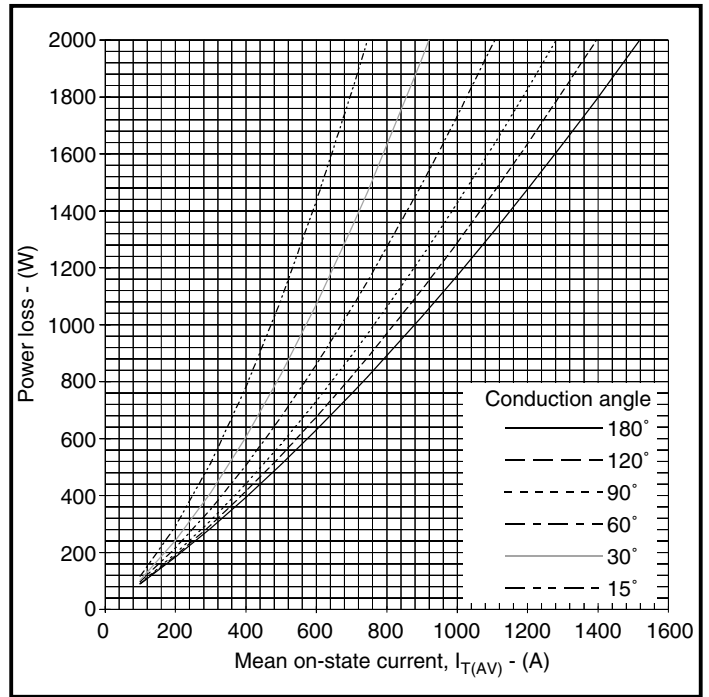


Fig.5 Sine wave power dissipation

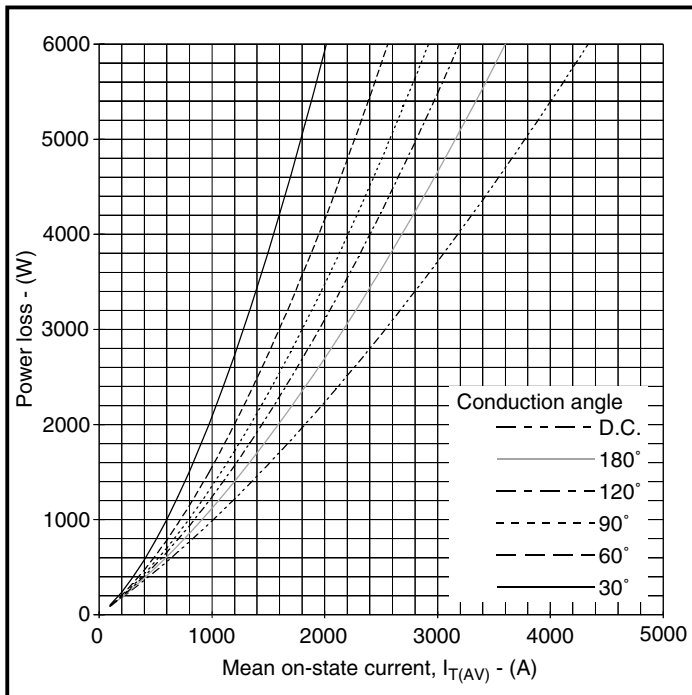


Fig.6 Square wave power dissipation

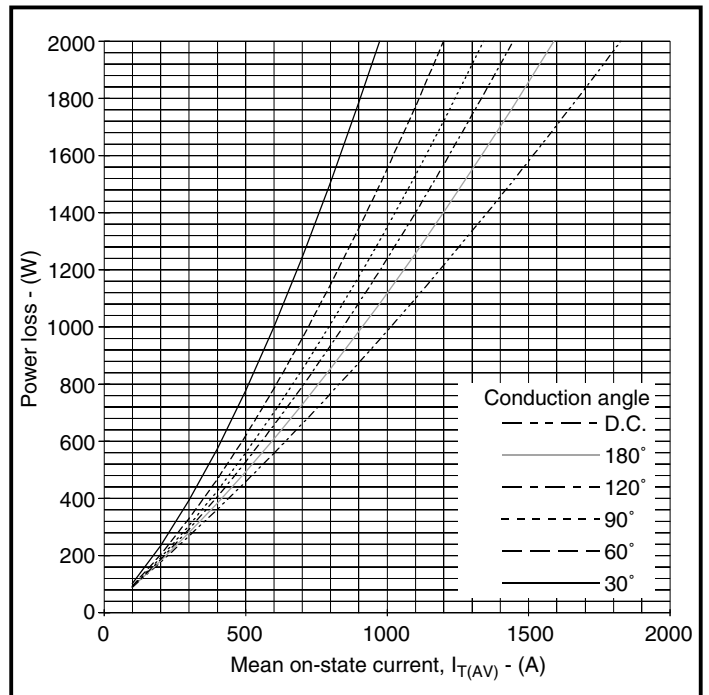
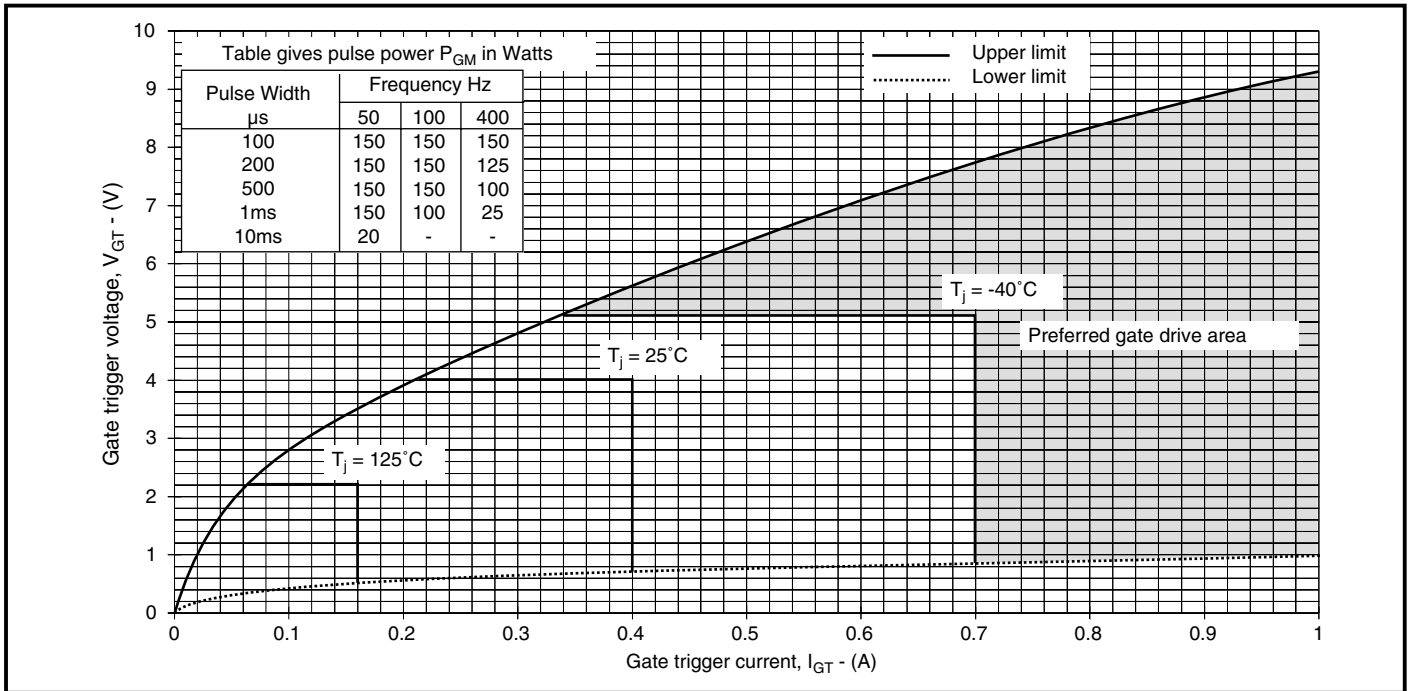
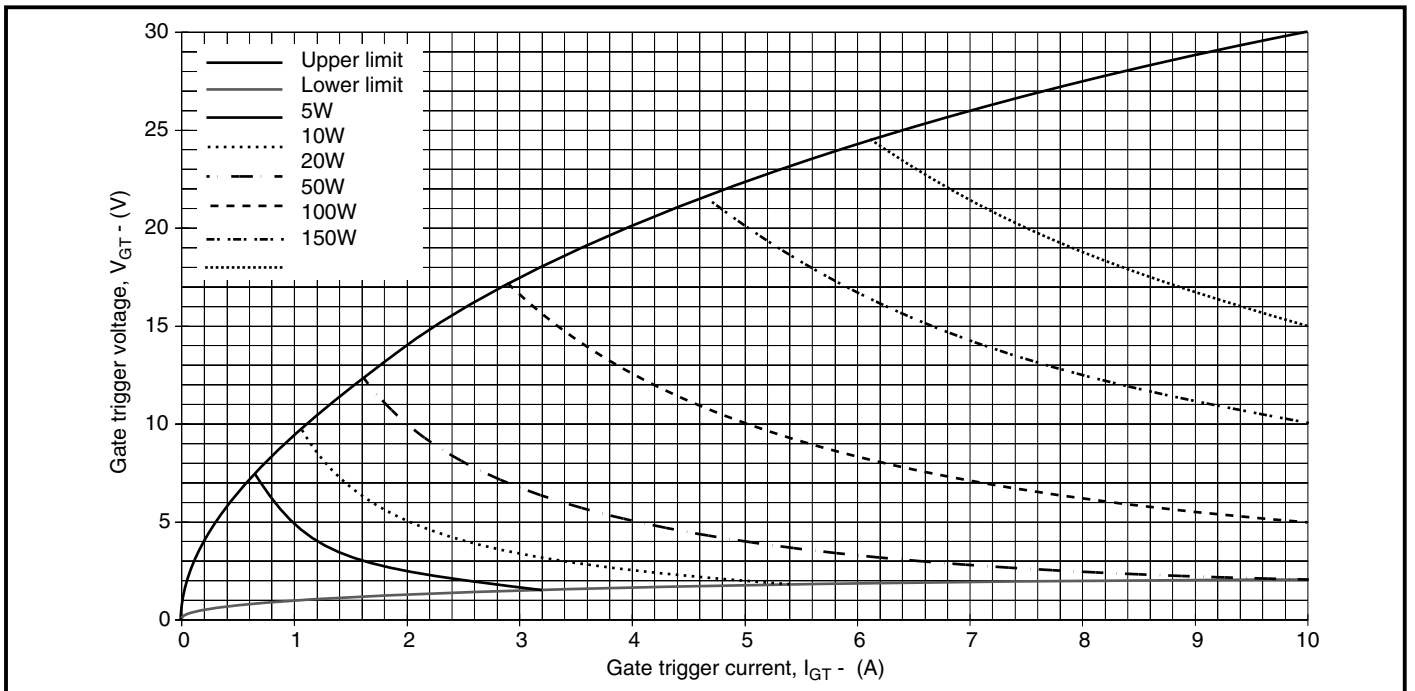


Fig.7 Square wave power dissipation



**Fig.8 Gate characteristics**



**Fig.9 Gate characteristics**

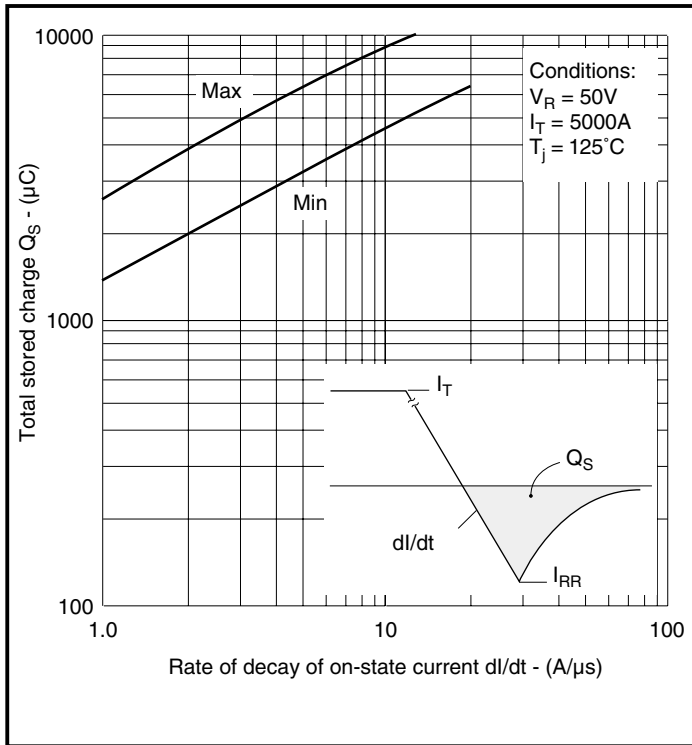


Fig.10 Stored charge

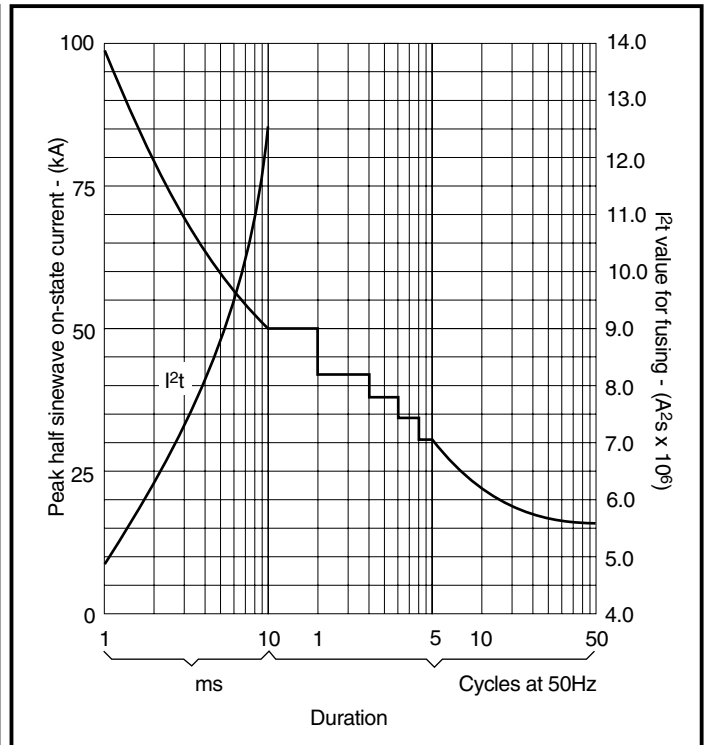


Fig.11 Surge (non-repetitive) on-state current vs time (with 50%  $V_{RRM}$  at  $T_{case} = 125^\circ C$ )

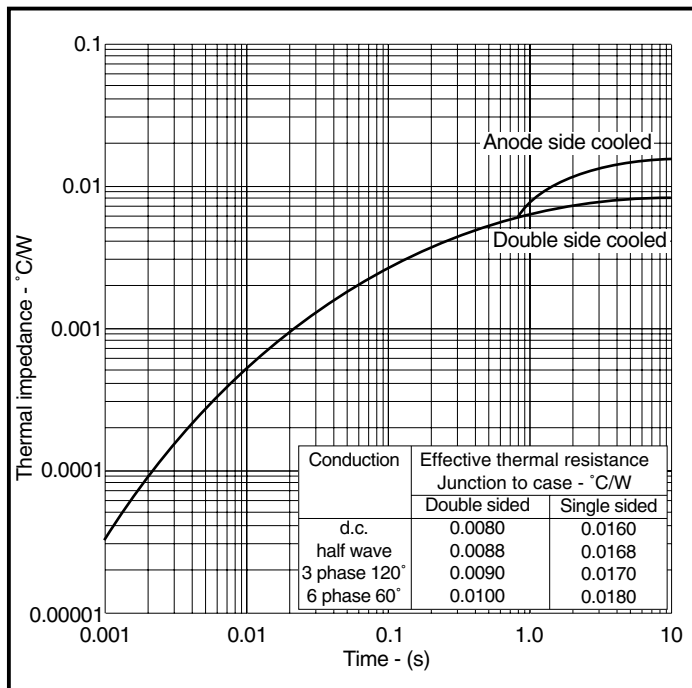
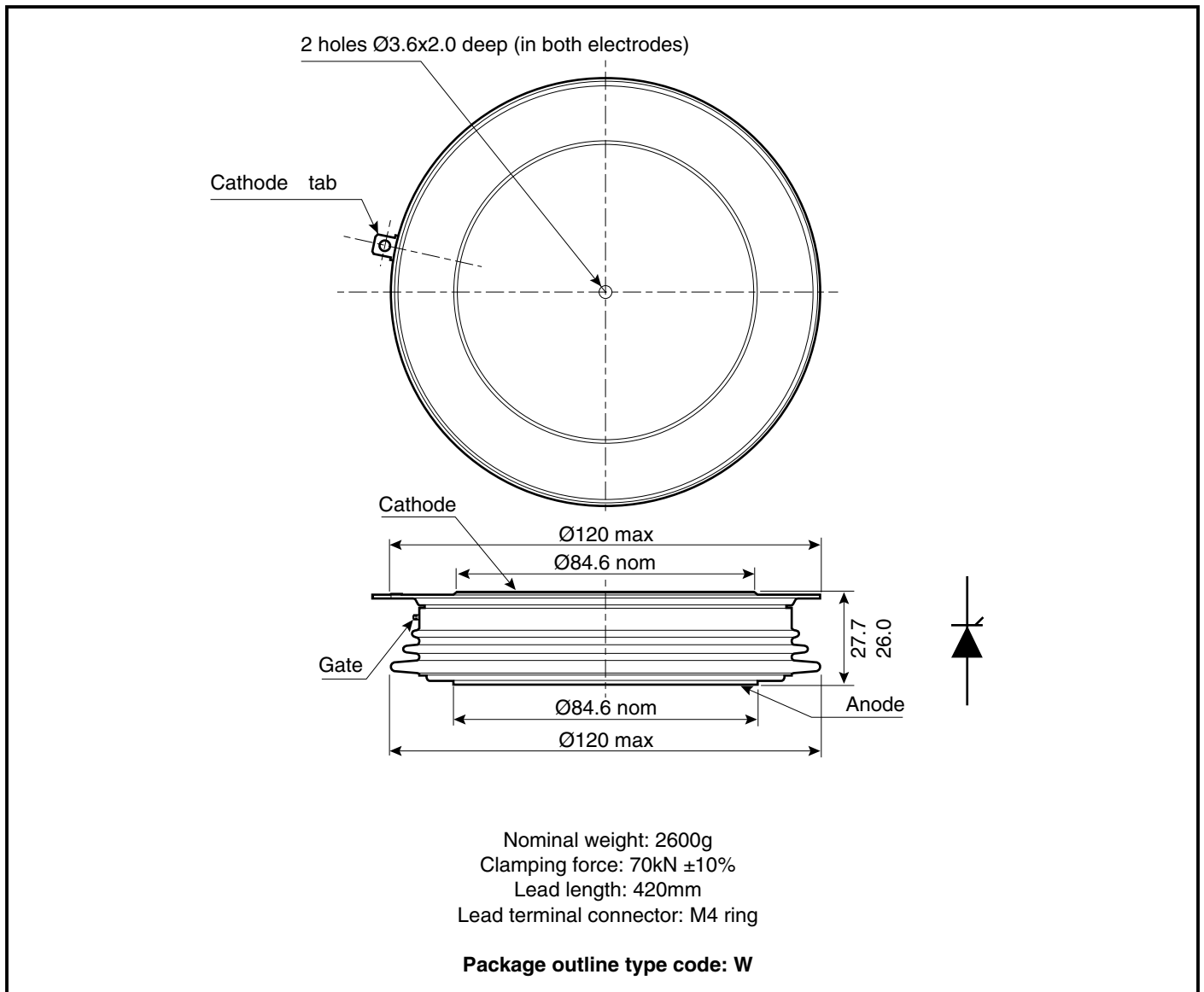


Fig.12 Maximum (limit) transient thermal impedance - junction to case (°C/W)

**PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



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## POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

## HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



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